

SHINDENGEN

Schottky Rectifiers (SBD)

Dual

SF10SC9

90V 10A

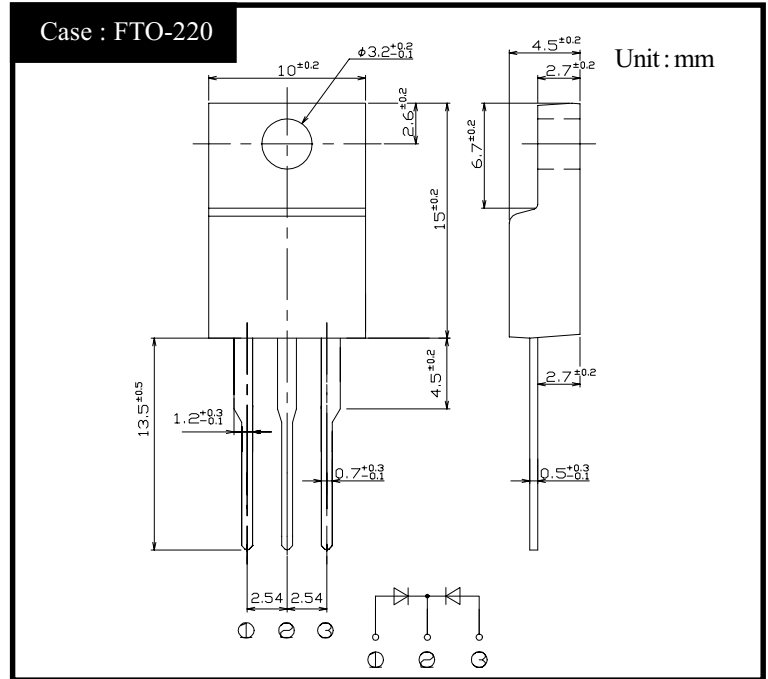
FEATURES

- Tj150°C
- P_{RRSM} avalanche guaranteed
- Fully Isolated Molding
- Dielectric strength 2kV guaranteed

APPLICATION

- Switching power supply
- DC/DC converter
- Home Appliances, Office Equipment
- Telecommunication

OUTLINE DIMENSIONS



RATINGS

● Absolute Maximum Ratings (If not specified T_c=25°C)

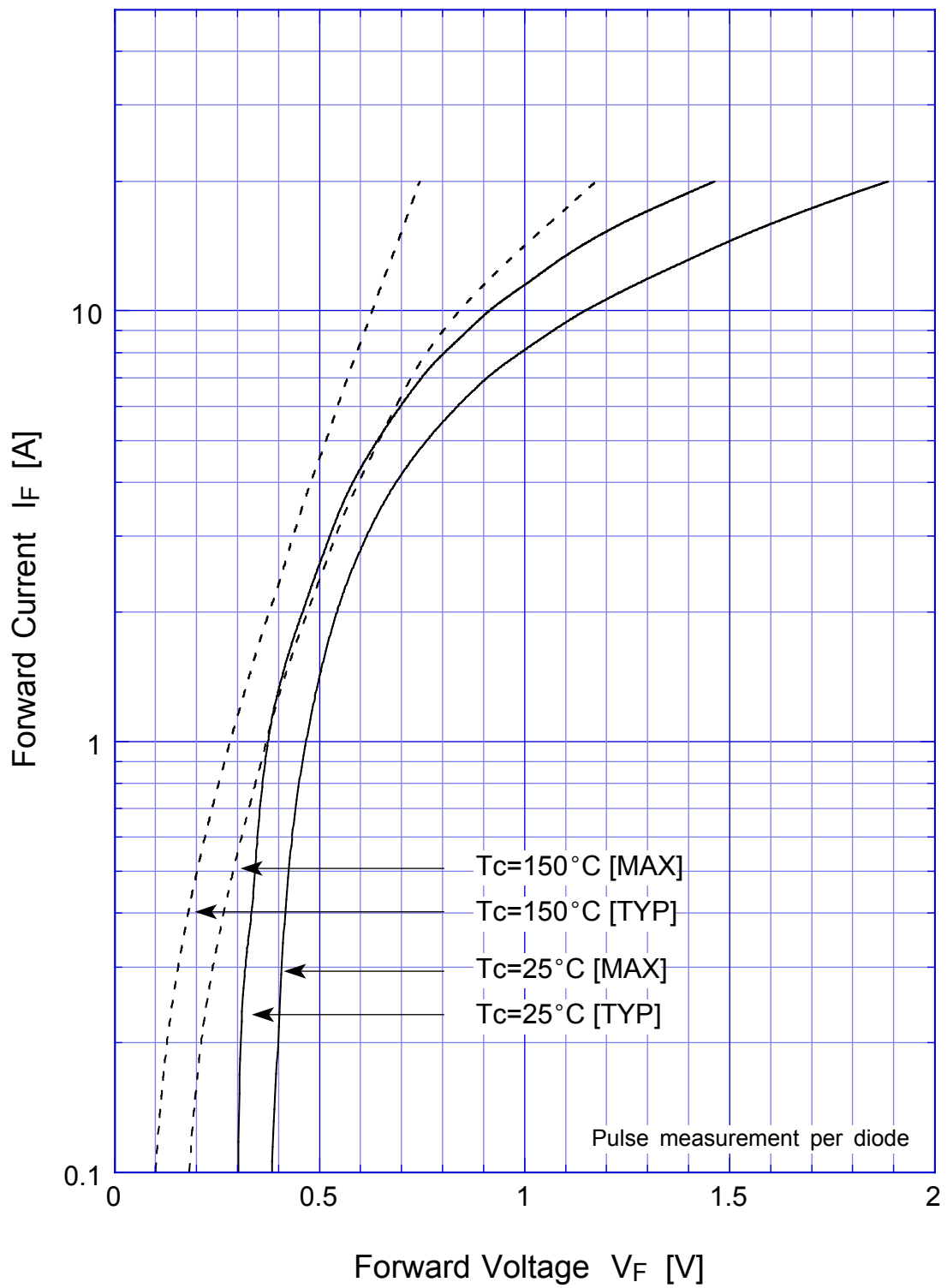
Item	Symbol	Conditions	Ratings	Unit
Storage Temperature	T _{stg}		-40~150	°C
Operating Junction Temperature	T _j		150	°C
Maximum Reverse Voltage	V _{RM}		90	V
Repetitive Peak Surge Reverse Voltage	V _{RRSM}	Pulse width 0.5ms, duty 1/40	100	V
Average Rectified Forward Current	I _O	50Hz sine wave, R-load, Rating for each diode I _o /2, T _c =120°C	10	A
Peak Surge Forward Current	I _{FSM}	50Hz sine wave, Non-repetitive 1 cycle peak value, T _j =125°C	100	A
Repetitive Peak Surge Reverse Power	P _{RRSM}	Pulse width 10 μs, Rating of per diode, T _j =25°C	330	W
Dielectric Strength	V _{dis}	Terminals to case, AC 1 minute	2	kV
Mounting Torque	TOR	(Recommended torque:0.3N·m)	0.5	N·m

● Electrical Characteristics (If not specified T_c=25°C)

Item	Symbol	Conditions	Ratings	Unit
Forward Voltage	V _F	I _F =5A, Pulse measurement, Rating of per diode	Max.0.75	V
Reverse Current	I _R	V _R =V _{RM} , Pulse measurement, Rating of per diode	Max.3	mA
Junction Capacitance	C _j	f=1MHz, V _R =10V, Rating of per diode	Typ.185	pF
Thermal Resistance	θ _{jc}	junction to case	Max.2.3	°C/W

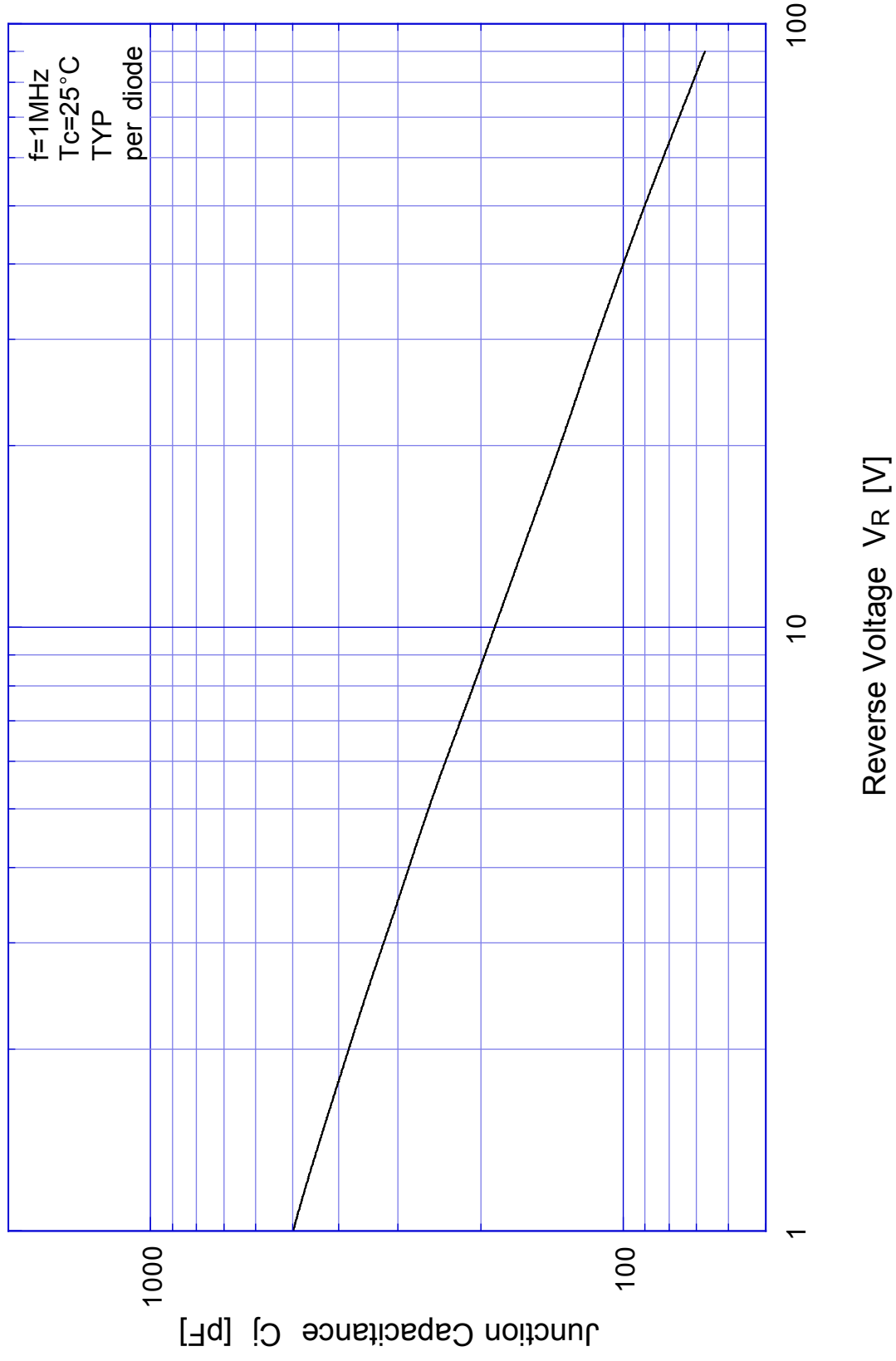
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Forward Voltage



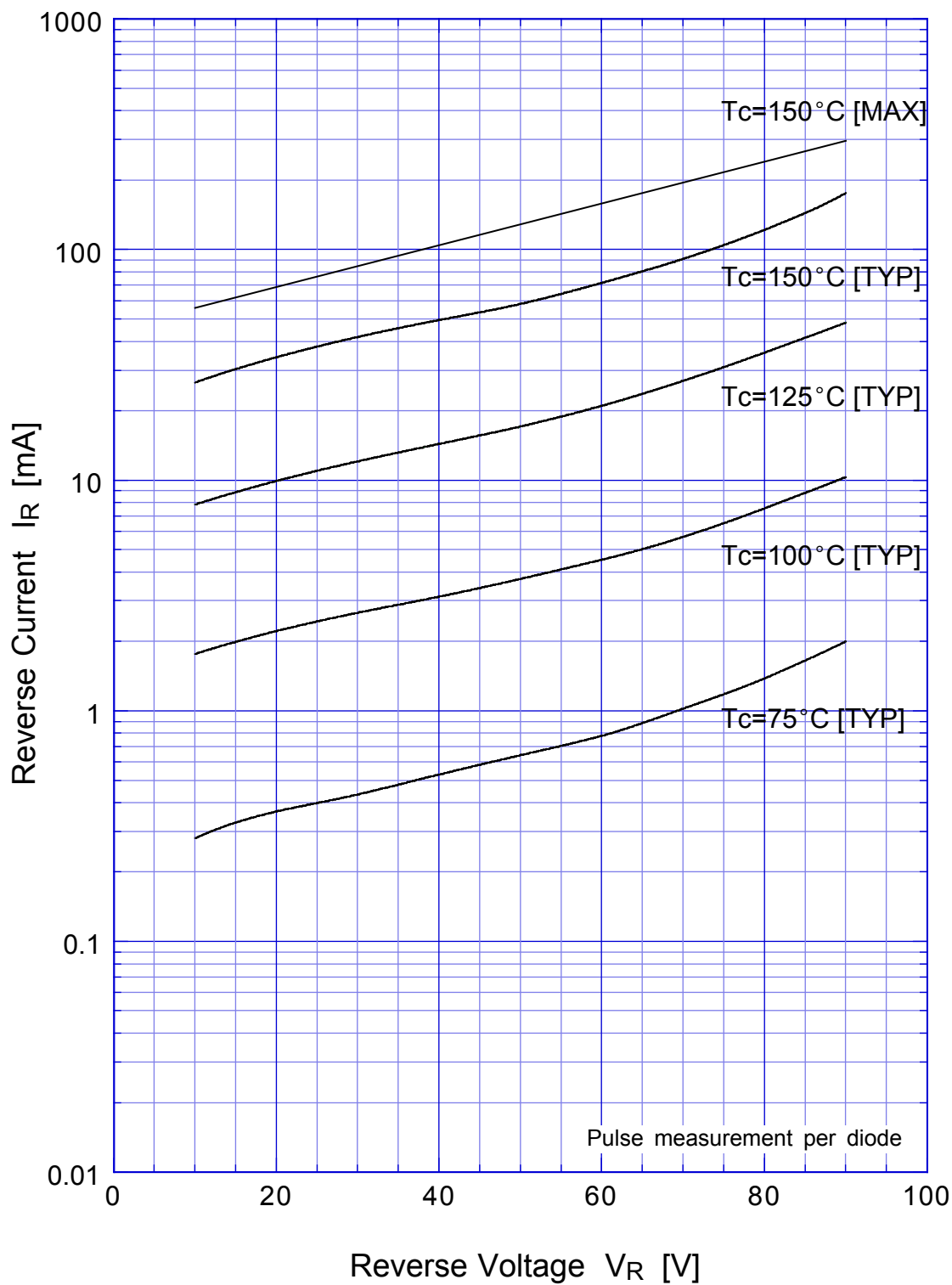
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Junction Capacitance

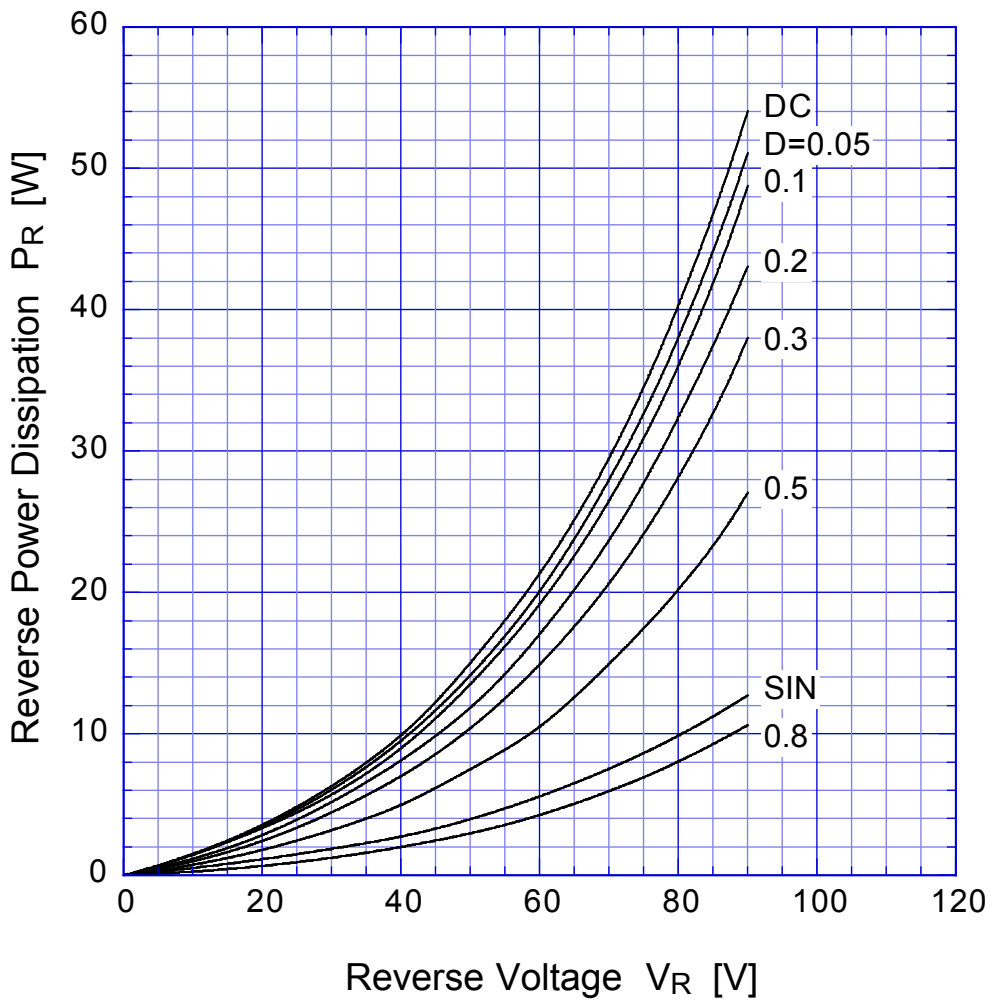


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Reverse Current



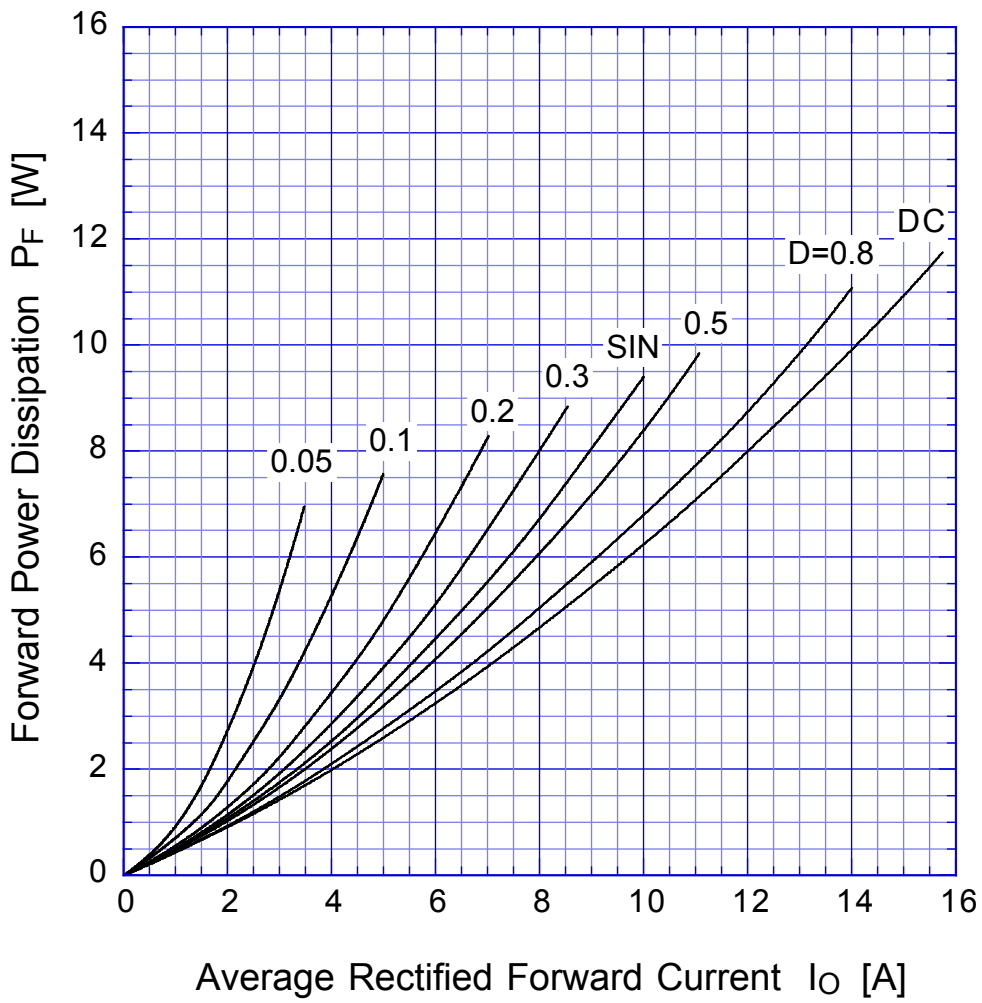
SF10SC9 Reverse Power Dissipation



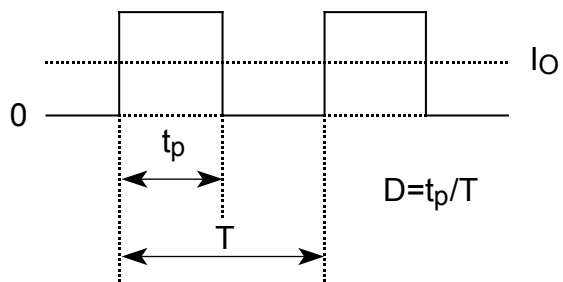
$T_j = 150^\circ\text{C}$



SF10SC9 Forward Power Dissipation

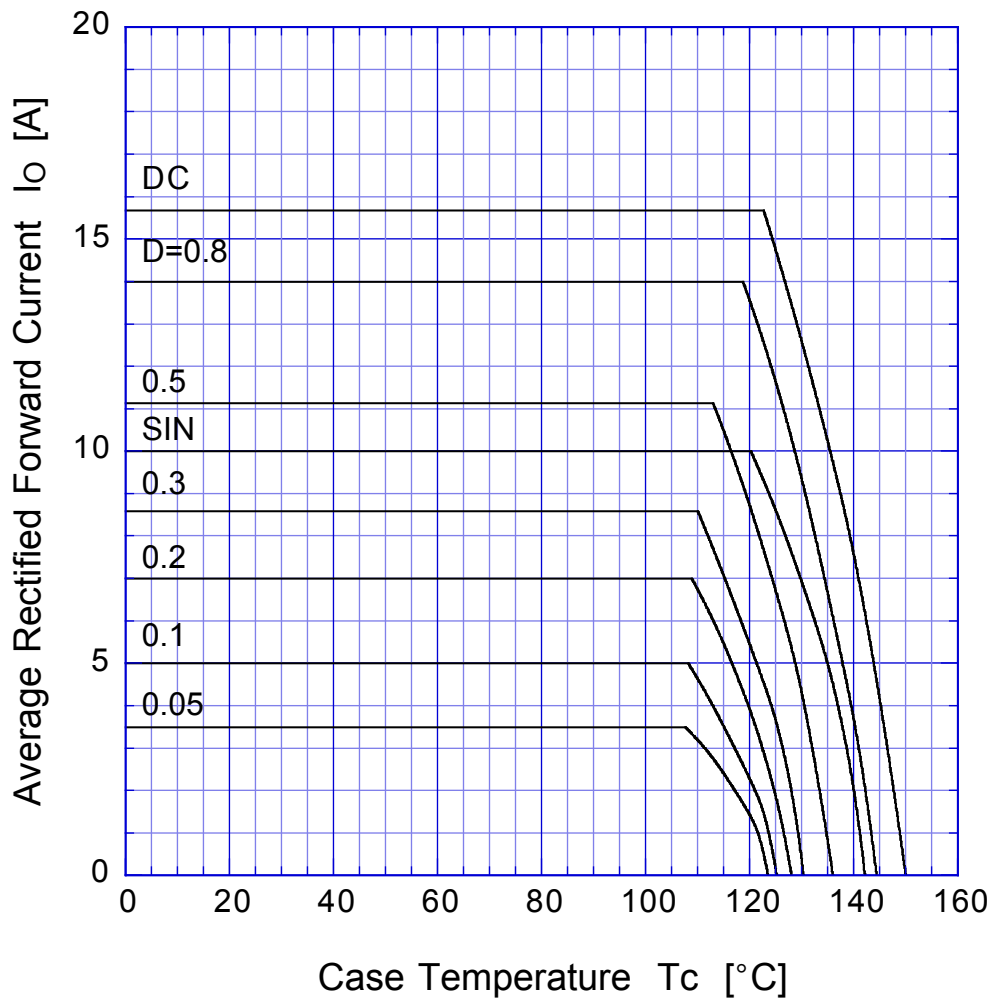


$T_j = 150^\circ\text{C}$



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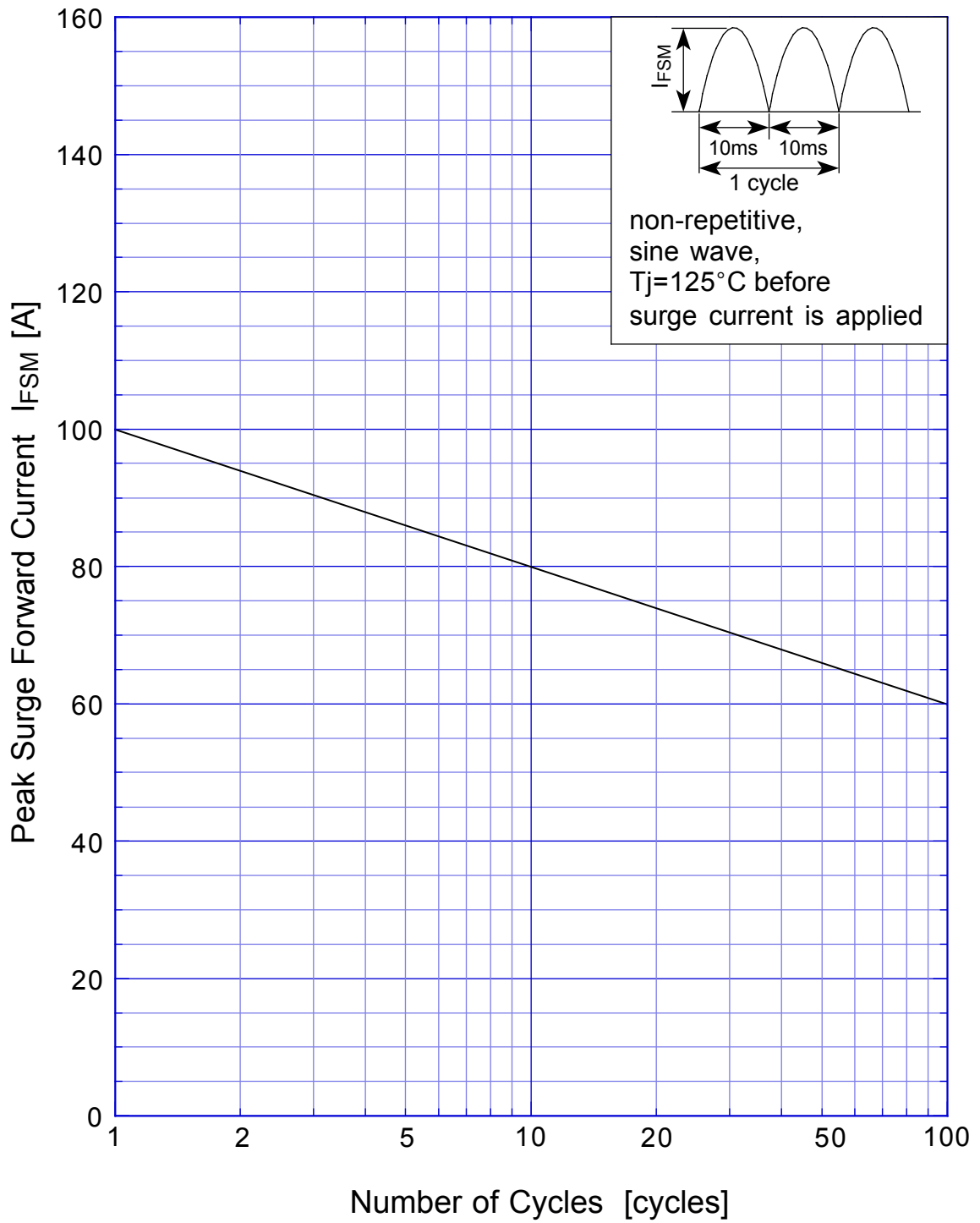
Derating Curve



$V_R = 45V$



SF10SC9 Peak Surge Forward Capability



SBD Repetitive Surge Reverse Power Derating Curve



SBD

Repetitive Surge Reverse Power Capability

